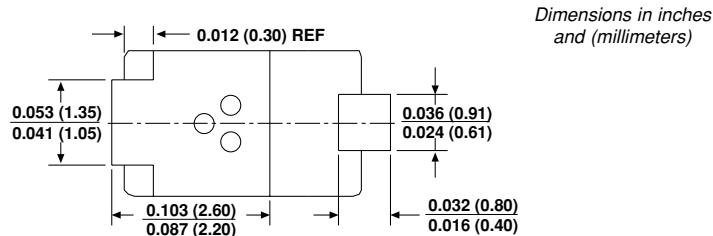
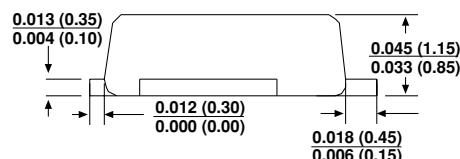
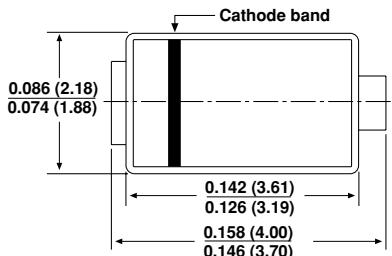




High Current Density Surface Mount Ultrafast Rectifiers

Case Style SMP



Features

- Reverse Voltage 50 to 200 V
- Forward Current 1.0 A
- Reverse Recovery Time 15 ns
- Very low profile - typical height of 1.0mm
- For surface mount application
- Glass passivated chip junction
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- Built in strain relief, ideal for automated placement
- High temperature soldering:
260°C maximum/10 seconds at terminals
- Meets MSL level 1 per J-STD-020C

Mechanical Data

Case: SMP

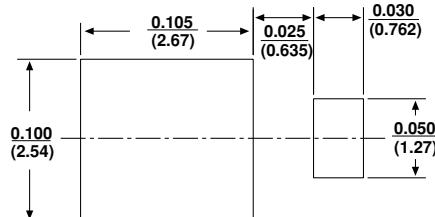
Terminals: Matte Tin plated (E3 Suffix) leads, solderable per J-STD-002B and MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Weight: 0.0009 oz., 0.024 g

Epoxy meets UL 94V-0 flammability rating

Mounting Pad Layout



Maximum Ratings & Thermal Characteristics (TA = 25°C unless otherwise noted.)

Parameter	Symbol	ES1PA	ES1PB	ES1PC	ES1PD	Unit
Device marking code		EA	EB	EC	ED	
Maximum reverse voltage	VRM	50	100	150	200	V
Maximum average forward rectified current see Fig.1	IF(AV)			1.0		A
Peak forward surge current 10ms single half sine-wave superimposed on rated load	IFSM			30		A
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL} R _{θJC}			105 15 20		°C/W
Operating junction and Storage temperature range	T _J , T _{STG}			-55 to +150		°C

Electrical Characteristics (TA = 25°C unless otherwise noted.)

Parameter	Symbol	Value	Unit
Maximum instantaneous forward voltage ⁽²⁾ at IF=0.6A, TJ=25°C at IF=1A, TJ=25°C	VF	0.865 0.920	V
Maximum reverse current TJ = 25°C at rated VRM ⁽²⁾ TJ = 125°C	I _R	5.0 500	μA
Maximum reverse recovery time at IF=0.5A, I _R =1A, I _{rr} =0.25A	trr	15	ns
Typical reverse recovery time at TJ=25°C at IF = 1.0A, VR = 30V dv/dt = 50A/μs, I _{rr} = 10% IRM TJ=100°C	trr	25 30	ns
Typical reverse recovery time at TJ=25°C at IF = 1.0A, VR = 30V dv/dt = 50A/μs, I _{rr} = 10% IRM TJ=100°C	Qrr	8 10	nC
Typical junction capacitance at 4.0V, 1MHz	C _J	10	pF

Notes: (1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0mm copper pad areas. R_{θJL} is measured at the terminal of cathode band. R_{θJC} is measured at the top centre of the body

(2) Pulse test: 300μs pulse width, 1% duty cycle

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Maximum Forward Current Derating Curve

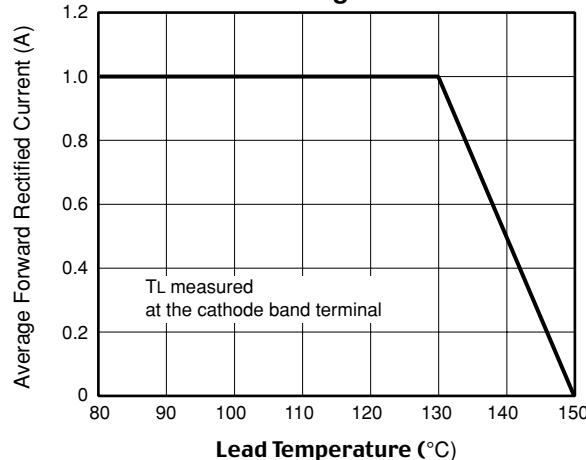


Fig. 3 – Typical Instantaneous Forward Characteristics

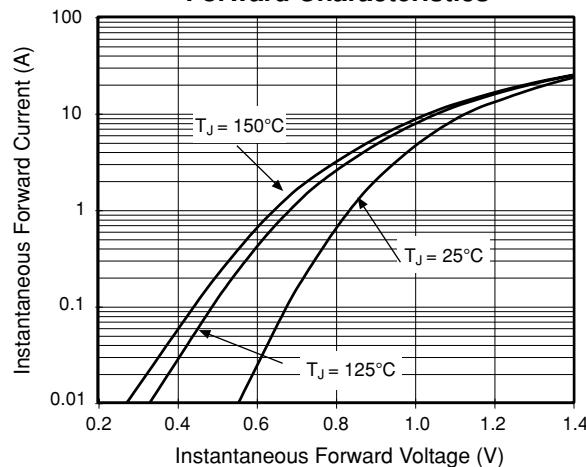


Fig. 5 – Typical Junction Capacitance

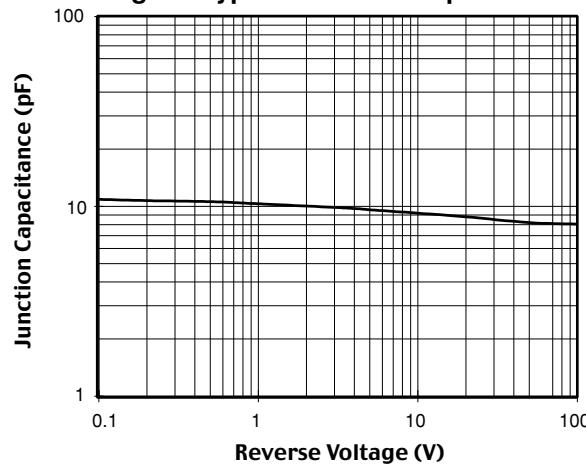


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

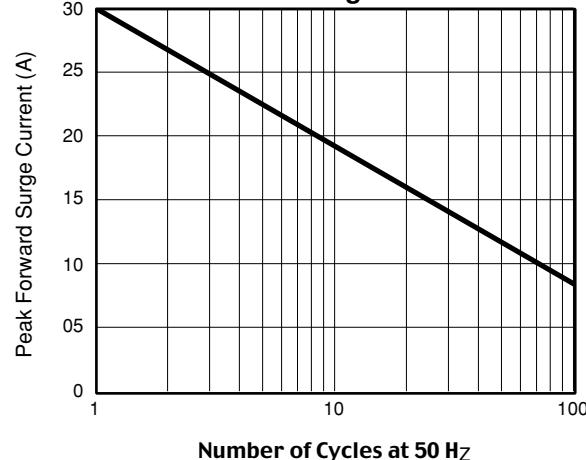


Fig. 4 – Typical Reverse Leakage Characteristics

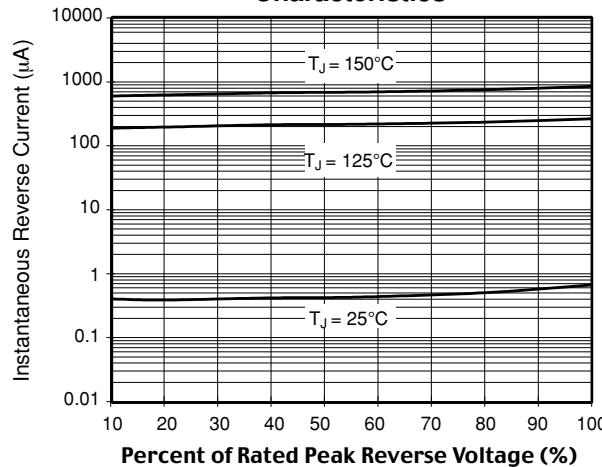


Fig. 6 – Typical Transient Thermal Impedance

